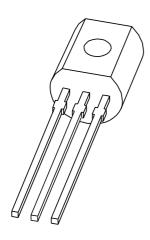
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



BC556; BC557 PNP general purpose transistors

Product specification Supersedes data of 1997 Mar 27 1999 Apr 15





### PNP general purpose transistors

BC556; BC557

**Product specification** 

### **FEATURES**

• Low current (max. 100 mA)

• Low voltage (max. 65 V).

### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

PNP transistor in a TO-92; SOT54 plastic package. NPN complements: BC546 and BC547.

#### **PINNING**

PIN	DESCRIPTION
1	emitter
2	base
3	collector

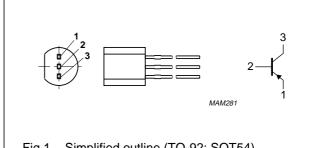


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BC556		_	-80	V
	BC557		_	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BC556		_	-65	V
	BC557		_	<b>-45</b>	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	-5	V
I <sub>C</sub>	collector current (DC)		_	-100	mA
I <sub>CM</sub>	peak collector current		_	-200	mA
I <sub>BM</sub>	peak base current		_	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

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### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	250	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

### **CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

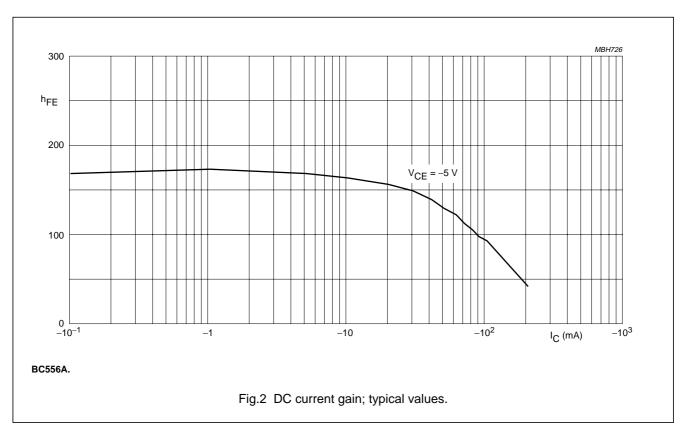
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = -30 V	_	-1	-15	nA
		$I_E = 0$ ; $V_{CB} = -30 \text{ V}$ ; $T_j = 150 ^{\circ}\text{C}$	_	_	-4	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = -5 V	_	_	-100	nA
h <sub>FE</sub>	DC current gain BC556 BC557 BC556A BC556B; BC557B BC557C collector-emitter saturation	$I_C = -2$ mA; $V_{CE} = -5$ V; see Figs 2, 3 and 4 $I_C = -10$ mA; $I_B = -0.5$ mA	125 125 125 220 420	- - - - -	475 800 250 475 800 –300	mV
OLGA	voltage	$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -5 \text{ mA}$	_	-180	-650	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = -10 \text{ mA}$ ; $I_B = -0.5 \text{ mA}$ ; note 1 $I_C = -100 \text{ mA}$ ; $I_B = -5 \text{ mA}$ ; note 1	_	-750 -930	_	mV mV
V <sub>BE</sub>	base-emitter voltage	$I_C = -2 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ note } 2$ $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ note } 2$	-600 -	-650 -	-750 -820	mV mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$	_	3	_	pF
C <sub>e</sub>	emitter capacitance	$I_C = i_c = 0$ ; $V_{EB} = -0.5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	10	_	pF
f <sub>T</sub>	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$	100	_	_	MHz
F	noise figure	$I_{C} = -200 \ \mu A; \ V_{CE} = -5 \ V; \ R_{S} = 2 \ k\Omega;$ $f = 1 \ kHz; \ B = 200 \ Hz$	_	2	10	dB

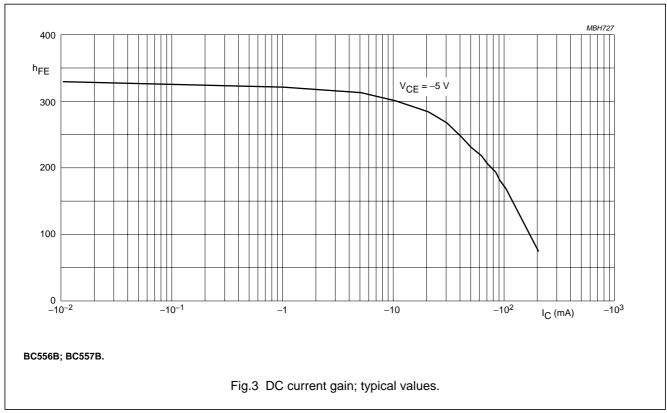
### Notes

- 1.  $V_{BEsat}$  decreases by about –1.7 mV/K with increasing temperature.
- 2. V<sub>BE</sub> decreases by about –2 mV/K with increasing temperature.

### PNP general purpose transistors

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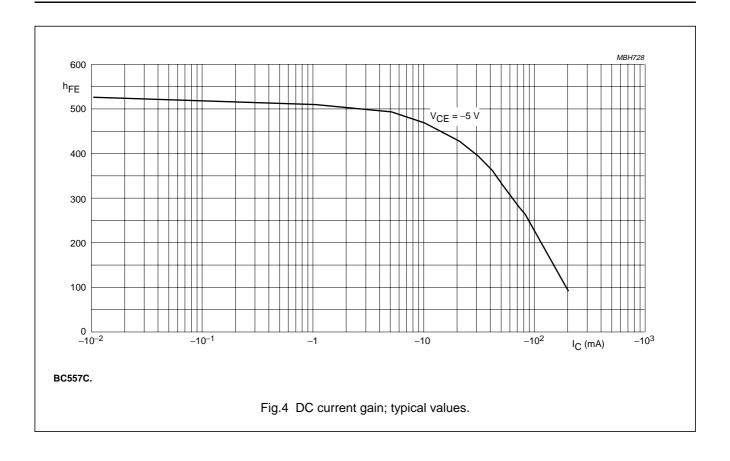


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### PNP general purpose transistors

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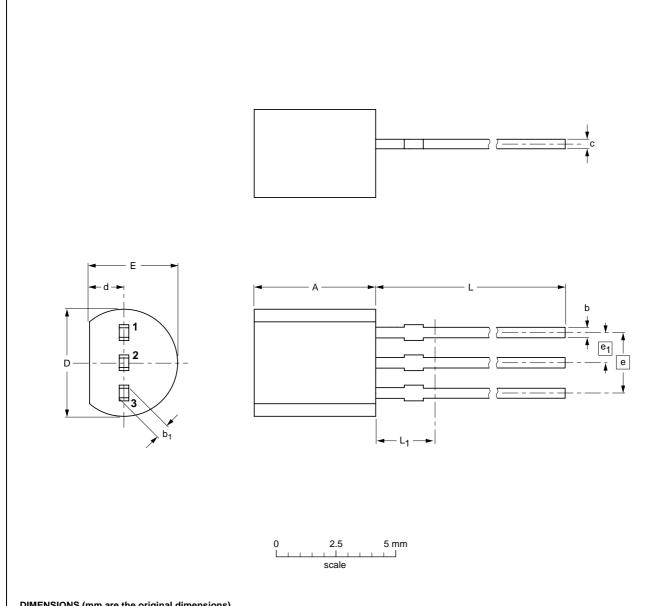
### PNP general purpose transistors

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### **PACKAGE OUTLINE**

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



### **DIMENSIONS** (mm are the original dimensions)

UNIT	Α	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43			97-02-28	

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### PNP general purpose transistors

BC556; BC557

#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification

### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### LIFE SUPPORT APPLICATIONS

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